# VS-VSKJS403/100

**Vishay Semiconductors** 





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AAP Gen 7 (TO-240AA)

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub> 400 A					
V <sub>R</sub>	100 V				
Package	AAP Gen 7 (TO-240AA)				
Circuit configuration Two diodes common anode					

#### **MECHANICAL DESCRIPTION**

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

#### FEATURES

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation
- Low thermal resistance
- UL approved file E78996
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- Easy mounting on heatsink

#### **ELECTRICAL DESCRIPTION / APPLICATIONS**

The VS-VSKJS409/150 Schottky rectifier common anode has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UNITS					
I <sub>F(AV)</sub>	Rectangular waveform	400	А				
V <sub>RRM</sub>		100	V				
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	23 000	А				
V <sub>F</sub>	200 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.83	V				
TJ	Range	-55 to +175	C°				

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-VSKJS403/100 UNITS						
Maximum DC reverse voltage	V <sub>R</sub>	100	V			
Maximum working peak reverse voltage	V <sub>RWM</sub>	100	v			

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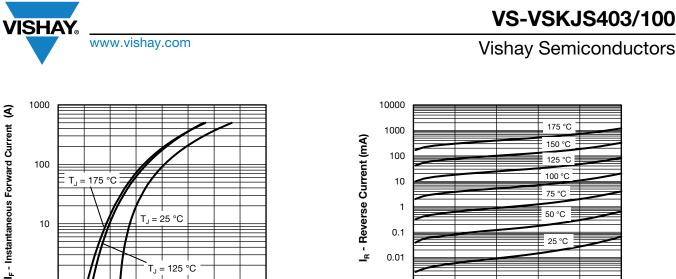
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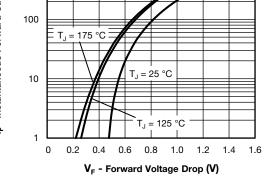
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ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS			
Maximum average forward per module		50 % duty cycle at $T_{\rm C}$ = 121 °C, rectangular waveform		400			
current per leg	I <sub>F(AV)</sub>	30% duty cycle at $1C = 121$ C	200				
Maximum peak one cycle	<b>1</b>	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with	23 000	A		
non-repetitive surge current	IFSM	10 ms sine or 6 ms rect. pulse	rated V <sub>RRM</sub> applied	2600			
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 5.5 A, L = 1 m	15	mJ			
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to ze Frequency limited by T <sub>J</sub> maxim	1	А			

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
		200 A	T.I = 25 °C	0.99	v	
Maximum forward valtage drep	V	400 A	1j=25 C	1.3		
Maximum forward voltage drop	V <sub>FM</sub>	200 A	T.I = 125 °C	0.83		
		400 A	$1_{\rm J} = 125$ C	1.09		
Maximum reverse leakage current	I <sub>RM</sub>	$T_J = 25 \ ^{\circ}C$	$V_{\rm B}$ = Rated V <sub>B</sub>	6	mA	
Maximum reverse leakage current		T <sub>J</sub> = 125 °C	VR - naleu VR	120		
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal rang	5500	pF		
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		5.0	nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs		
Maximum RMS insulation voltage	V <sub>INS</sub>	50 Hz	3000 (1 min) 3600 (1 s)	V		

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C
Maximum thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	0.32	°C/W
Typical thermal resistance, case to heatsink per module		R <sub>thCS</sub>		0.1	
Approximate weight				75	g
Approximate weight				2.7	oz.
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the	4	Nm
	busbar		spread of the compound.	3	
Case style			JEDEC®	TO-240AA co	ompatible





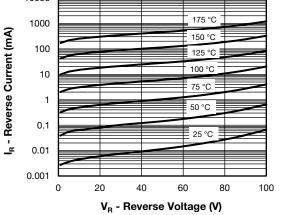


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

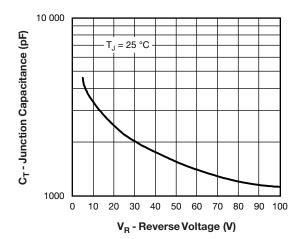


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

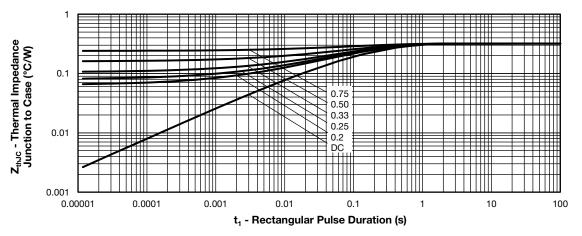


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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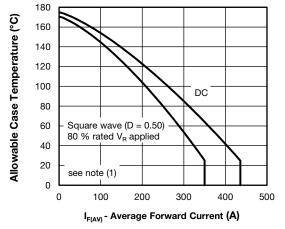
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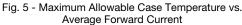
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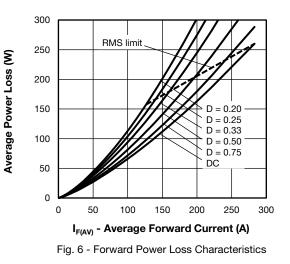


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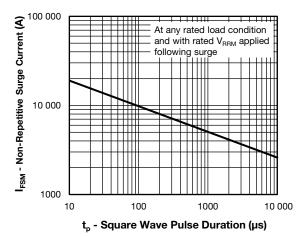


Fig. 7 - Maximum Non-Repetitive Surge Current

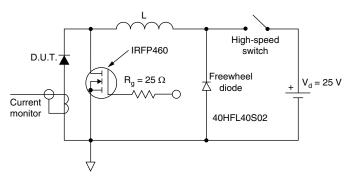


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \ - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

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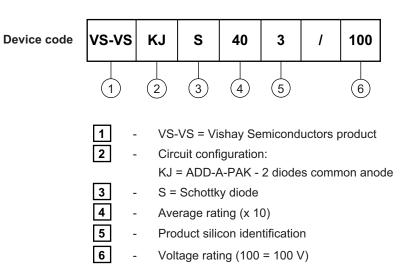
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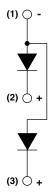
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#### **CIRCUIT CONFIGURATION**



LINKS TO RELATED DOCUMENTS				
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## **ADD-A-PAK Generation VII - Diode**

#### **DIMENSIONS** in millimeters (inches)





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